

# Toy-MC for gain fluctuations simulation in digitization



With inputs from Davide

27/07/20



#### Gain & fluctuations

So far, a constant value of 1y/2eV deposit energy is used as conversion factor (for LEMON)

### $\rightarrow$ we have to describe charges collection and gain fluctuations

Start from the number of primary ionization electrons (N<sub>primary</sub>) and consider (*in a simple statistical model*):

1) The probability that an electron, produced in the drift zone, arrives in the transfer area crossing a channel of the GEM foil (electron transparency);

2) The number of secondary electrons produced in the **multiplication** in a GEM foil.



# Gain & fluctuations – primary electrons

Unfortunately, our simulations (both G4 and SRIM) do not return the number of primary electrons but only the energy loss

 $\rightarrow$  we have to find a walkaround to estimate N<sub>primary</sub> and its fluctuations

For the moment focus on the other parts of the problem...  $\rightarrow$  Use the 55Fe case (good also for exp comparison):

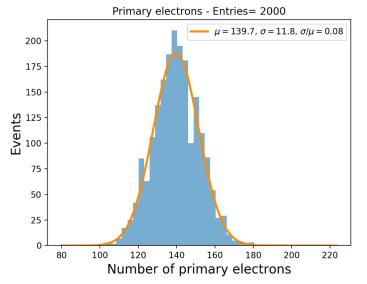
- The mean number of primary electrons in He is  $\overline{N_{primary}}$  = 5900 [eV] /42 [eV/pair] = 140

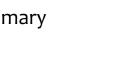
 $\rightarrow$  Generate  $N_{primary}$  according to a Poisson distribution

Shouldn't we consider a Fano factor (which is quite small for He mixtures...)?

$$\sigma = \sqrt{F \cdot \overline{N_{\text{primary}}}} \rightarrow \sigma / \mu \sim 0.05 \text{ if } F \sim 0.25$$

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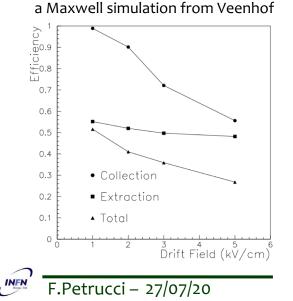


#### Gain & fluctuations – electron transparency

From simulations we can assume for each primary electron:

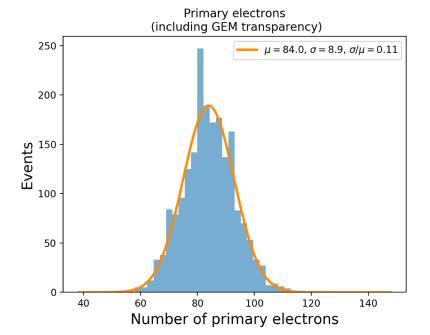
• *ε*~0.5 ÷ 0.6

(low drift field,  $\varepsilon_{Coll}$  saturates at 1 and  $\varepsilon_{Extr}$  smoothly increasing)



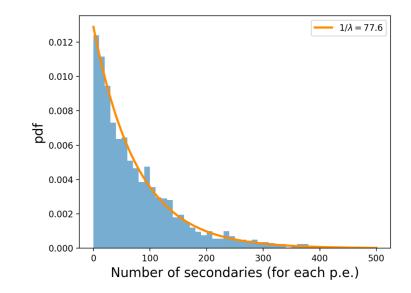
Generate the number of electrons to be considered in the multiplication (n.e.<sub>GEM</sub>)

from a binomial distribution with parameters  $N_{primary}$  and p=0.6

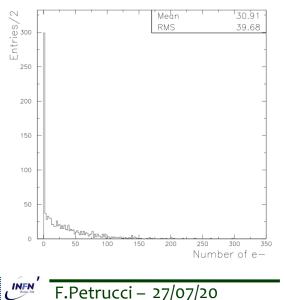


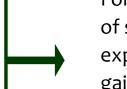
# Gain & fluctuations – multiplication (I)

the number of secondaries is described by an exponential (leaving the bin at o that is the inefficiency) For each electron to be multiplied (n.e.<sub>GEM</sub>) a number of secondaries is generated according to an exponential distribution with  $\mu = \sigma = 80$  (assumed GEM gain) and then added to obtain the total number of secondaries



#### a simulation from Pinci?

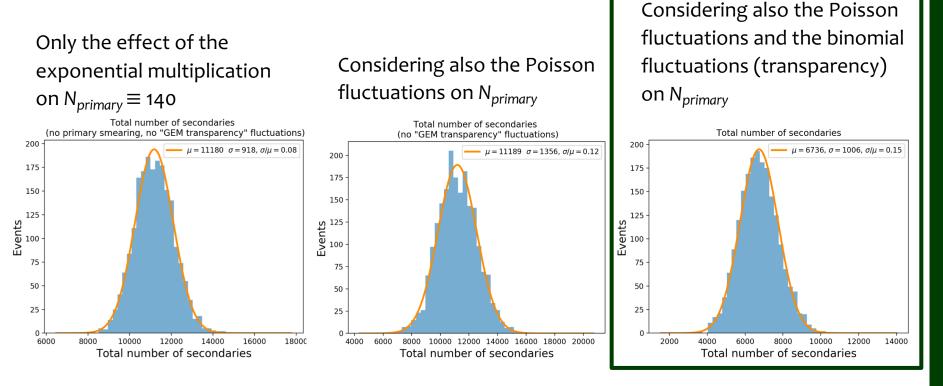








# Gain & fluctuations – multiplication (II)



Gain fluctuations induced by the other two GEMs foils is too time-consuming but should definitly be negligible (at least in this semplified model)

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